

I. Number	Hits	Search Text	DB	Time stamp
1	245	cmos WITH rectifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 15:43
2	280	cmos WITH (cathode or anode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 15:43
3	262	(cmos WITH (cathode or anode)) not (cmos WITH rectifier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 15:43
4	1463	(nmos and pmos) near5 series	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 15:46
5	894	257/350.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:13
6	989	257/288.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:13
7	1987	257/347.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
8	137	257/338.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
9	1326	257/355.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
10	568	257/356.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
11	400	257/357.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
12	1073	257/368.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
13	1786	257/369.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14
14	566	257/371.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:14

15	8331	257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:15
16	399	(257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (sio or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:16
17	398	((257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (sio or sion)) not (cmos WITH (cathode or anode))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:15
18	398	((257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (sio or sion)) not (cmos WITH (cathode or anode))) not (cmos WITH rectifier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:15
19	1671	(257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (soi or sion)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:16
20	173	((257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (soi or sion)) and (cathode or anode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:16
21	112	((257/350.ccls. or 257/288.ccls. or 257/347.ccls. or 257/338.ccls. or 257/355.ccls. or 257/356.ccls. or 257/357.ccls. or 257/368.ccls. or 257/369.ccls. or 257/371.ccls.) and (soi or sion)) and (cathode or anode)) and cmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/26 16:16
-	0	(nmos and pmos) near3 (shared adj diffusion)	USPAT; US-PGPUB	2003/05/28 14:11
-	3	(nmos and pmos) SAME (shared adj diffusion)	USPAT; US-PGPUB	2002/12/12 18:55
-	13	(shared adj diffusion) and (nmos and pmos)	USPAT; US-PGPUB	2002/12/12 19:06
-	104	(nmos and pmos) near3 series	USPAT; US-PGPUB	2003/11/26 15:46
-	46	((nmos and pmos) near3 series) and substrate	USPAT; US-PGPUB	2002/12/12 20:48
-	639	257/350.ccls.	USPAT; US-PGPUB	2003/11/26 15:46
-	1	("6465768").PN.	USPAT	2002/12/13 15:07
-	1	("6274911").PN.	USPAT	2002/12/13 15:07
-	1	("6355960").PN.	USPAT	2002/12/13 15:07
-	1	("6392860").PN.	USPAT	2002/12/13 15:08
-	0	("6498357").PN.	USPAT	2002/12/13 15:08
-	1	("6437407").PN.	USPAT	2002/12/13 15:13
-	1	("20020084490").PN.	USPAT; US-PGPUB	2002/12/13 15:14
-	1	("20020076876").PN.	USPAT; US-PGPUB	2002/12/13 15:14
-	82394	((nmos and pmos) near3 ((shared or shorted) near3 (source and drain))) or cmos	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 16:12

-	10178	((nmos and pmos) near3 ((shared or shorted) near3 (source and drain))) or cmos) and 257/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 16:13
-	2052	((nmos and pmos) near3 ((shared or shorted) near3 (source and drain))) or cmos) and 257/\$6.ccls.) and (tft or soi or (silicon adj on adj insulator))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 17:13
-	1	("6090646").PN.	USPAT	2002/12/13 17:13
-	1	("5352291").PN.	USPAT	2002/12/15 19:01
-	1	("6090646").PN.	USPAT	2002/12/15 19:02
-	1	"589/347".PN.	USPAT	2002/12/15 19:13
-	1	("5639698").PN.	USPAT	2002/12/15 19:02
-	1	"5824573".PN.	USPAT	2002/12/15 19:13
-	1836	soi and diode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 14:13